

\* As vgs increases, VDS reduces & i'p increases If vi is negative, the a point moves down the load line. \* For FET to operate as a linear amplifier,

FET plus the transistor must be brased in the estimation

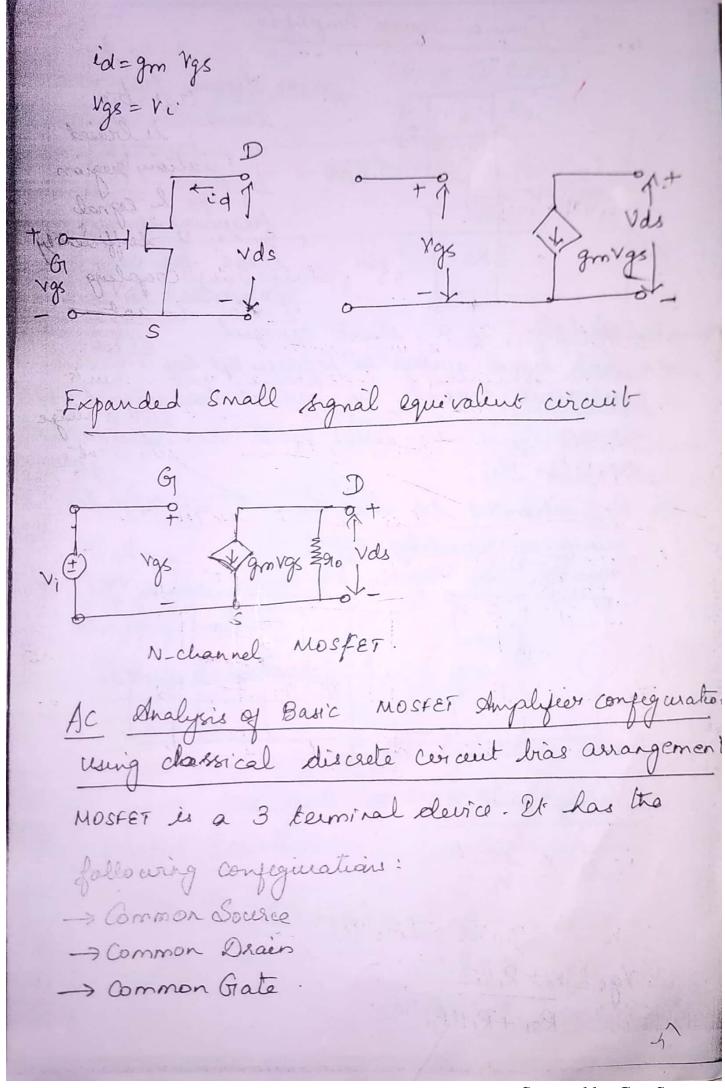
linear pordegion & i'p & Vols must be confused to the

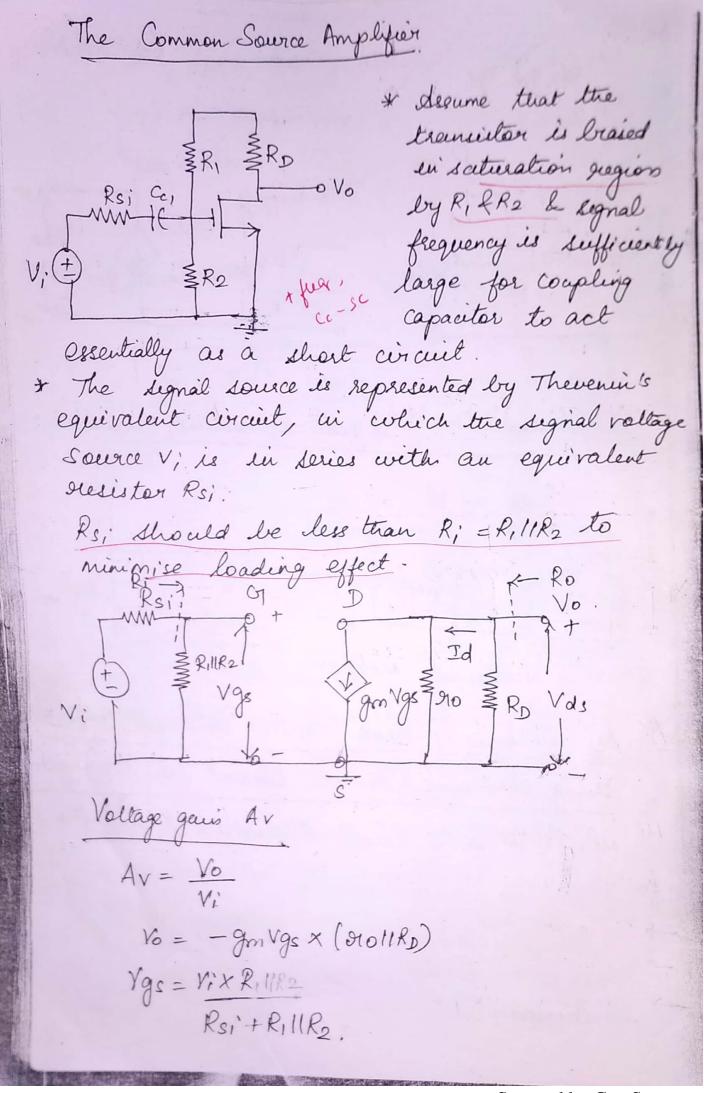
satisfaction Saluration region. Transistor parameters The instantaneous gate to source voltage is VGs = Vgsa + Vi = VGsa + Vgs ->0 Vorsa -> de component vgs -> ac component The instantaneous drain current  $d_D = kn \left( V_{CTS} - V_{TN} \right)^2 \rightarrow 2$ Substituting Equation (2) UD = Kn[Vasa + Vgs - VTN] = kn [(VGSQ-VTN) + Vgs] 2 -> (3a) in = Kn [ (Voisa - VTN) 2 + 2 (Vasa-VTN) vgs + Vgs

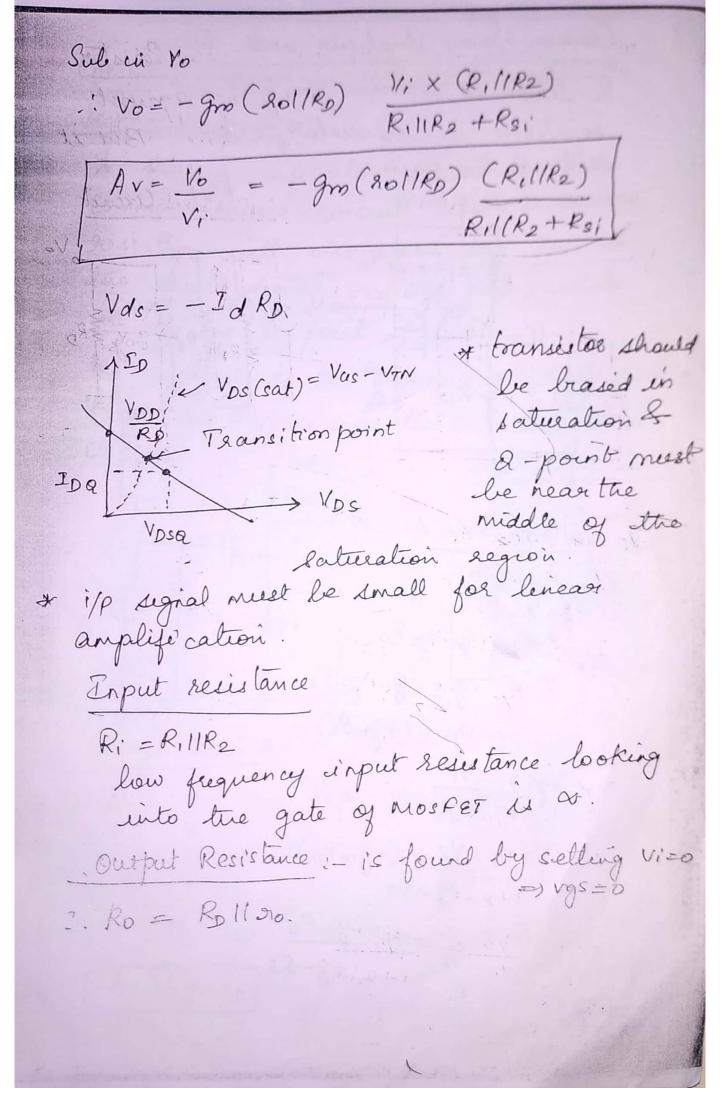
1st -> 3b) 2nd 389 In equation (36) 1st term is the dc or quiescent deaui curren

and term - time varying draw current component that is devearly related to vgs. 3 releven -> proportional to the square of Signal voltage. For sine i/p, This squared term froduces undesirable Karmonice, or non chinear distortion in The off voltage To minimise the harmonics, we require Vgs < <2(Vgsa - VTN) -> (1) Egn @ represents the small signal condition that must be satisfied by all linear amplifiers. Neglecting vgs. term, is = isa+id lirearity statal current can be separated into a dc & ac component. The ac-component of draw current is given by ed = 2 Kn (Vasa - VTN) Vgs id = | gm = 2 kn ( Vas - VTN) / - 5 gn = transconductance is a transfer expercial morning output coverent to supert voltage and can be thought of as the gain of the transistor = 2 kn (Vas-Vin) gm = 0 10 / Vgs = Vgsa = constant

from @ " (p = kn (vgs - VIN)) 100 = Kn ( Vg8a - VTN) 2. · Vgsa - VTN = ViDa. Sub in 5 gm= 2Kn Vipa I gm = 2 Jkn Ioa If vgs is small, gm is constant. With . Slope = gm a point in the Saturation region, the transistor operates as current Source that is linearly controlled by vgs. gm & Kn (function of width to length when the wealth of the transistor centreases the gain increases. Small signal squivalent circuit: VDS = VDD - CDRD.  $V_0 = Vds = -i p R_0$ .





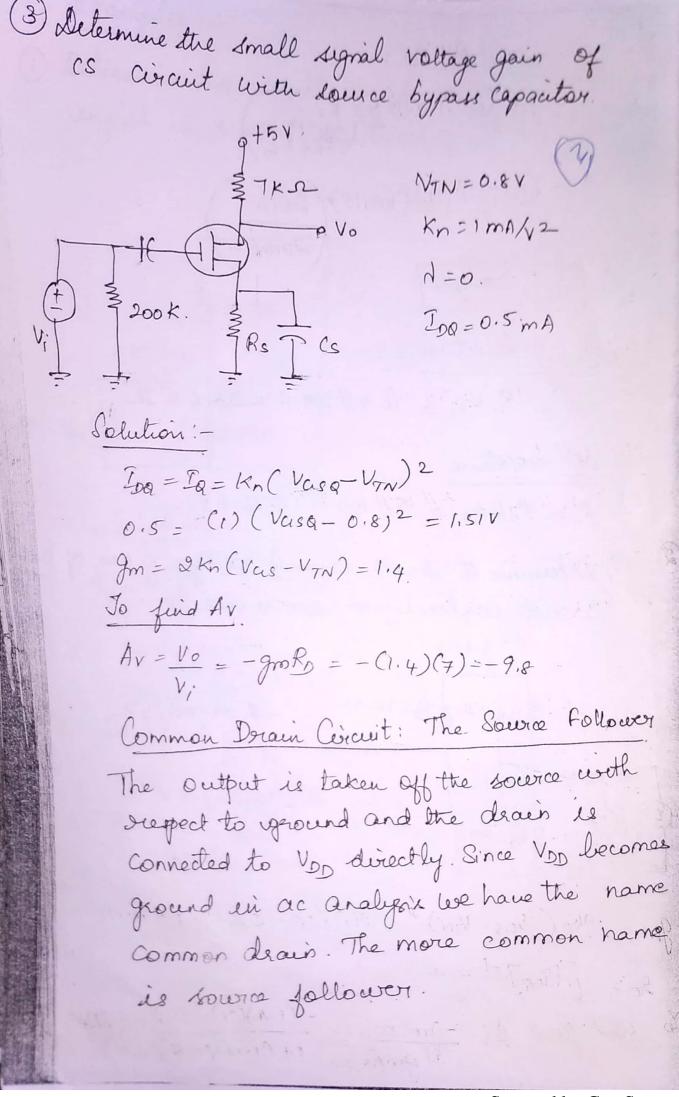


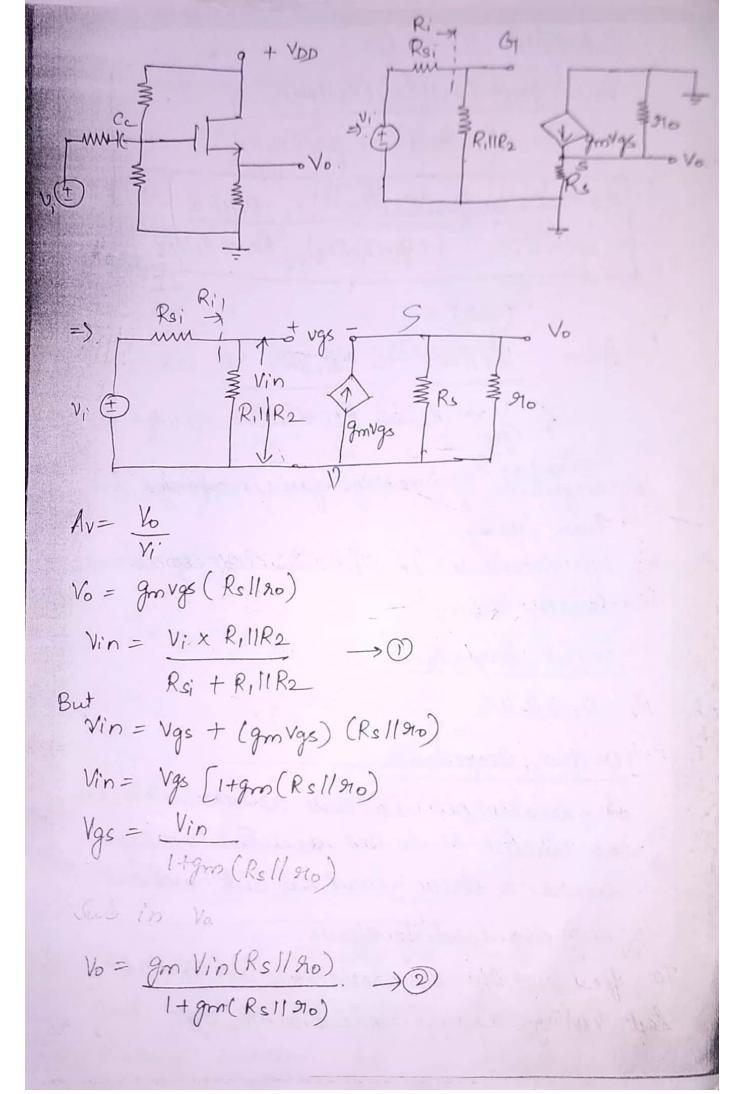
Common Source Amplifier with Source Resistor Rs tends to stabilise The Q-point against Vociations in transister parameters. But it Equivalent Circuit deduces the gain. Voltage Gain Av No= -gm Vgs Ro Vi = Vgs+ gm Vgs Rs = Vgs (1+gmls)

Common Source anciet with source Bypers Capaciton A lource capacitor added to the Common source circuit with a source resistor will numinies the loss in the small signal voltage gain, while maintaining &- point stability. for analysis, if the frequency is sufficiently large, the bypass capacitor acts as a short circuit. Equi valent Circuit Vollage Grain AV Vo = - gm Vgs KD Av= Vo : AV = 10 = - gmRD Av=-gmRD

Examples: 1) Determine the small signal voltage gain and support & output resistances of a amplifier. YTN = 1.5 Y Kn = 0.5 mA/V2 d = 0.01v-1. Solution: Av = -gm (rollRD) Ri gm = 2 Kn (Vasa - VTN) no = [dIDa] To find Vasa & For  $Vasa = \left(\frac{R_2}{R_1 + R_2}\right) V_{DD} = \left(\frac{99.1}{70.9 + 29.1}\right) (10) = 2.91$ IDa = Kn (Vasa - VTN) = (0.5) (2.91-1.5) = 1 mA To feel gon & no: Im = 2 Kn (Vasq-VTN) =2 (0.5)(2,91-1.5)= 1.41 mA/V 910= [1] = [(0:01)(1)] = 100KSL

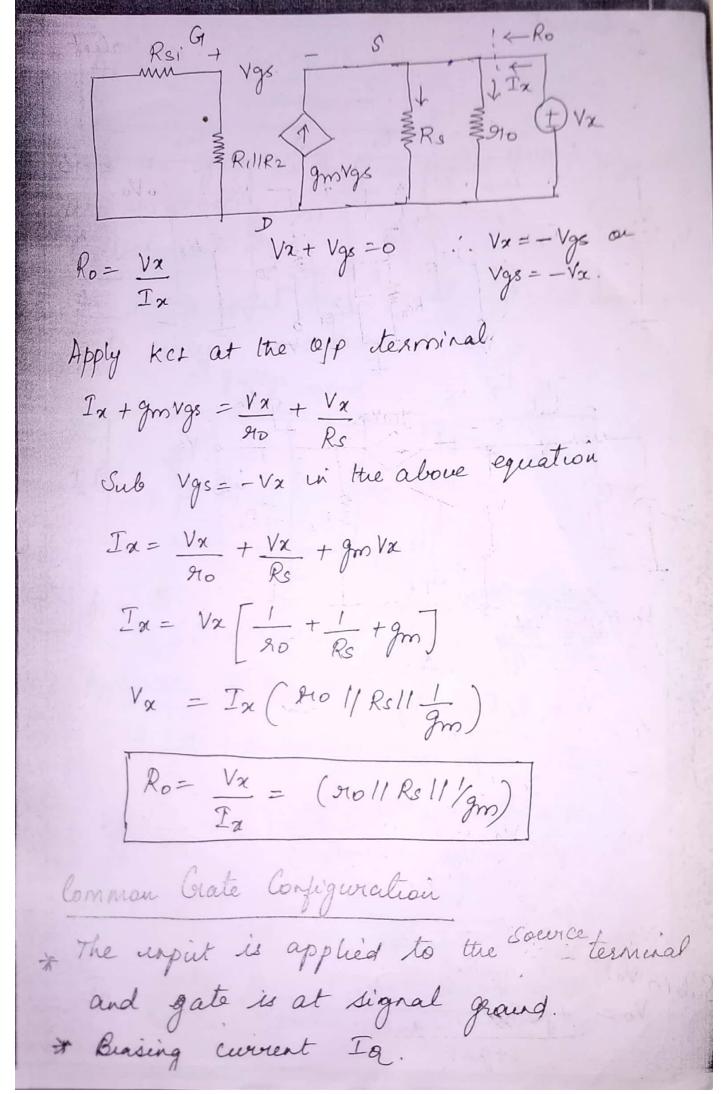
To calculate Av: Av= -gm (9011RD)(Ri Ri+Rsi)  $= (-1.41)(100115)\left(\frac{20.6}{20.644}\right)$ Av= -5.62/ Input resistance Ri = RillR2 = 70.9/129.1 = 20.6 KSZ OP resistance Ro= Roll 90 = 5/1 100 = 4.76 KSZ (2) Determine a small signal voltage gain of CS circuit containing a source resistor. 9 YN=0.8V MW 165 KSLAW RD=7KSL Kn=1mA/V2 A =0 Vasq=1.5 V. V; (1) 3 R2 = 100 \$ R5 = 0.5 K-12 IDQ = 0.5 mA VDSQ = 6.25 V. gm = 2kn ( Vas- VTN) = 2(1) (1.5-0.8) = 1.4 10.9 90= /120a] - = 00 To find Av: Av = -gmRD = -(1.4)(7) =-5.76 (+gmRs = 1+(1.4)(0.5)

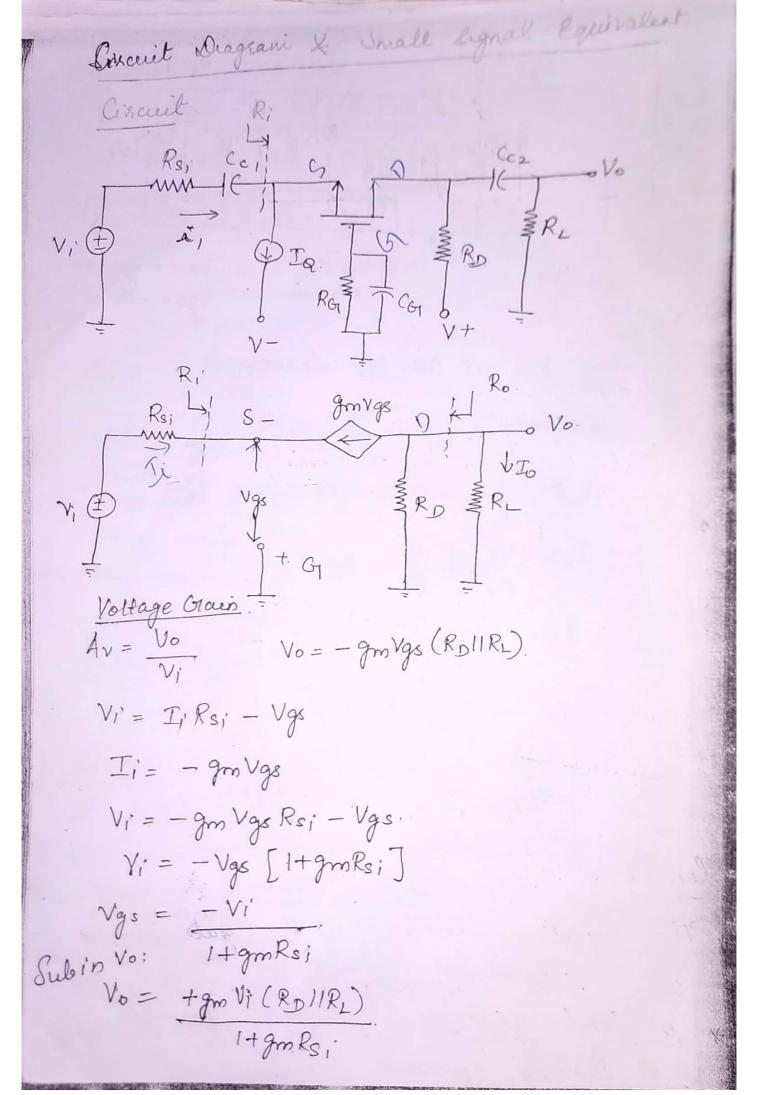




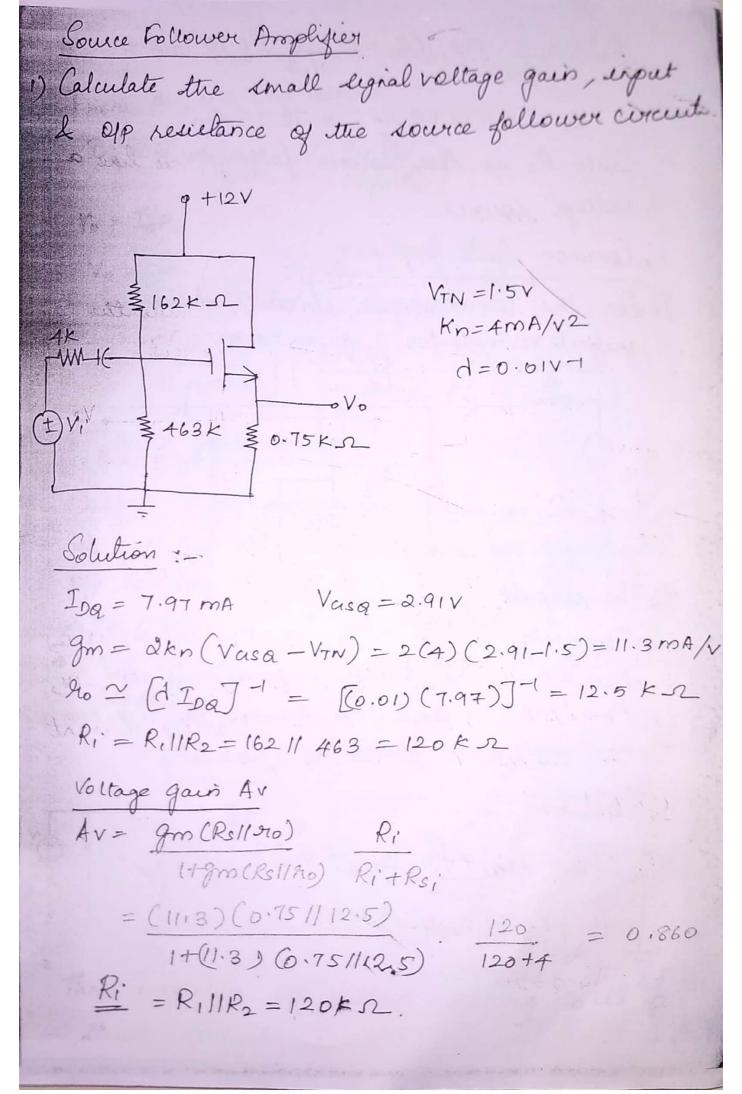
Scanned by CamScanner

Substitute ( in ( Vo = gmvi (RIIIRe) (Rs 1110) (Rsi +R,11R2)(-1+ gm (Rs1120)), Av = Vo = gm(Rs/120) . R.11R2 1+9m(RellRo) Rs,+ R1/1/R2 R. UR2 25/180 In + (Rs/10) Rsi+R,1/R2 \* magnitude of voltage gain is always less than unity. \* Of recistance is less than that of common Source circuit. Input Impedance  $R_i = R_1 / 1 R_2$ Output Impedance I small off resistance is desviable when the circuit is to act as ideal voltage Lource & drive load circuit without Suffering loading effects. To find the Off Resistance let Vi = 04 test voltage is applied to the op.





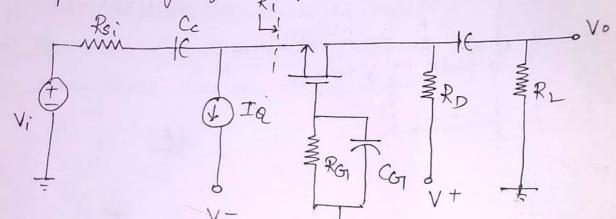
A'= \frac{I\_0}{I\_i} = \frac{g\_m R\_0 R\_{Si}}{(R\_0 + R\_L)(1+g\_m R\_{Si})} When RossRL & gmRs; >> 1 Ai 21 for CG circuit. Input Impedance \*. The input resistance is low. \* If the i/p signal is current, then low ip resistance has an advantage.  $R_i = \frac{-Vgs}{I}$ I'= - gm Vgs  $R_i = \frac{-Vgs}{-gmVgs} = \frac{V}{gm}$ Ri = Jam Output Resistance Ro= RD.



Ro = 0.0787KD = 78.7KD Since Ro is less, source follower acts line a voltage source.

Common gate Amplifier

1) For the common gate circuit, determine the output voltage for a given i p current.



The circuit parameters = are: IQ = 1mA, V = +5V, V = -5V,  $R_{0} = 100 k \Omega$ ,  $R_{0} = 4k \Omega$ ,  $R_{\perp} = 10 k \Omega$ , The transistar parameters are  $V_{TN} = 1V$ ,

Kn= 1mA/v2, and d=0. Assume the ijp convert

is 100 sincot leA & Rsi = 50 Ks.

Solution:

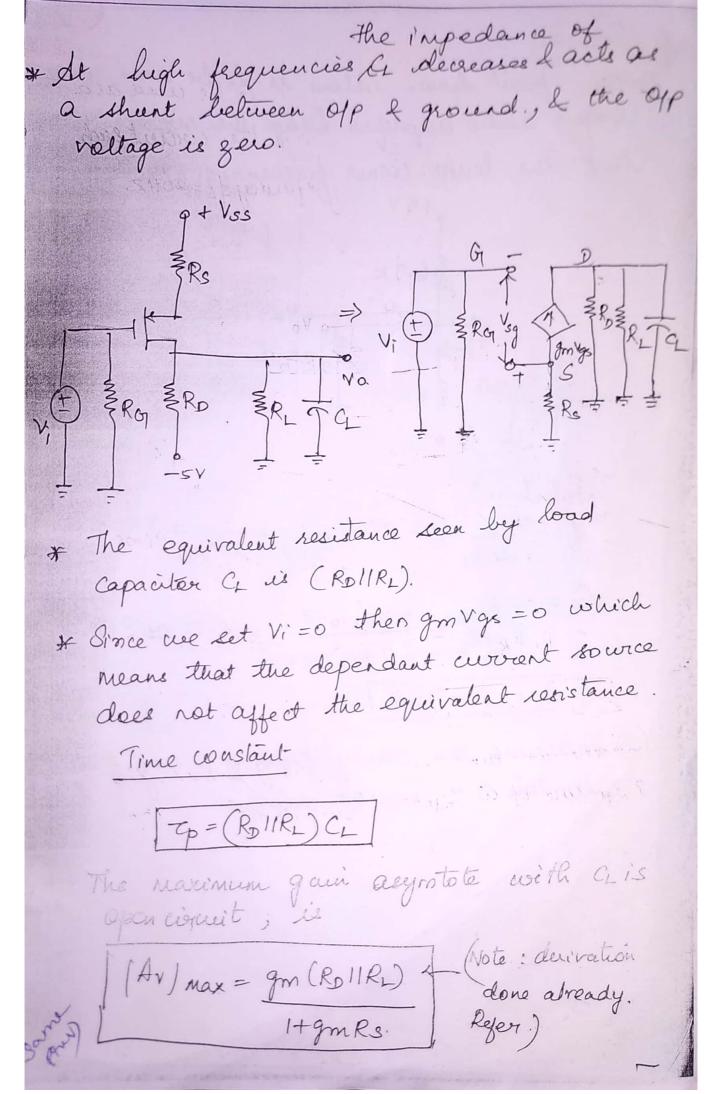
$$I_{R} = I_{DR} = k_n (V_{CISR} - V_{TN})^2$$

$$I = I (V_{CISR} - I)^2$$

$$V_{CISR} = 2V$$

9m = 2 Kn ( VOISR - VTN) = 2(1) (0-1) = 2 mA/N From Ai, we can write To = Ii (RD RD+RL) ( gmRsi) Vo = TORL Vo = Ii (RD RD+RL) (9m Rei XRL  $= \left[\frac{(10)(4)}{4+10}\right] \left[\frac{(2)(50)}{1+(2)(50)}\right] (0.1) \text{ Sinut}$ / Yo = 0.283 Sin wt V Output Coupling Capaciton: Common Source Ckt: fig shows a common source MOSFET with Of Coupling Capacitor \* Rsi ZZRGe . Les is neglected. \* of is connected to the load through a coupling capaciter. no is assumed to be as. THE STATE OF THE S -5V The maximum ofp voltage assuming cc is a Short circuit is,

| Volmax = gmvg (RD/1/RL) Vi = Vgs + gm Vgs Rs Vi = Vgs(1+gmRs) => Vgs = Vi Vo= gm\_Vi' (RD IIRL) 1+gmRs Vo = Avmax = gm (RollRL) 1+gm Rs The time constant is a function of the Effective resistance seen by capacitor (c) which is determined by setting independent sources equal to zero. Vi=0, gmVgs=0 then TS = Cc (RD+RL) 1 = - 1 ants Load capacitée Effects: \* hy shows a MosfET Common Source amplifier with a load resistor R. La load capacitée CL Connected to the Op. \* for the ac equivalent circuit Ho is assumed to lie os. \* The circuit is like a Low pass filter.



Example: D. The circuit shown below is to be used as a Comple audio amplifier. Design the circuit such that the lower corner frequency of = 20112. WI OKS WIOKS WIOKS Solution:

 $f = \frac{1}{2\pi \zeta} = 7.96 \text{ ms}$ 

Cc = TS = 7.96×10-3 = 4.77 ×10-7 F RD+RL 6.7×103+10×103

1 Cc = 0.477 MF

Determine the corner frequency & max gain asymtote of a MOSFET Simplifier